

## Monolithic Amplifier ERA-6SM+

500 DC to 4 GHz

#### **FEATURES**

- DC to 4 GHz
- Single Voltage Supply
- Internally Matched to 50Ω
- Unconditionally Stable
- Low Performance Variation Over Temperature
- Transient Protected
- Aqueous Washable
- Protected By US Patent 6,943,629



Generic photo used for illustration purposes only

CASE STYLE: WW107

+RoHS Compliant The +Suffix identifies RoHS Compliance. ur website for methodologies and qualific

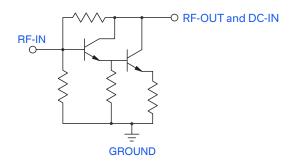
#### **APPLICATIONS**

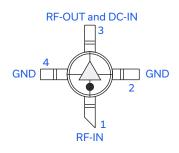
- · Cellular/ PCS/ 3G Base Station
- CATV, Cable Modem & DBS
- Fixed Wireless & WLAN
- · Microwave Radio & Test Equipment

#### **PRODUCT OVERVIEW**

ERA-6SM+ (RoHS compliant) is a wideband amplifier offering high dynamic range. It has repeatable performance from lot to lot. It is enclosed in a Micro-X package. ERA-6SM+ uses Darlington configuration and is fabricated using InGaP HBT technology. Expected MTTF is 350 years at +85°C case temperature.

#### SIMPLIFIED SCHEMATIC AND PIN DESCRIPTION





| Function   | Pin Number | Description  |  |
|--|------------|--|--|
| RF-IN  | 1          | RF input pin. This pin requires the use of an external DC blocking capacitor chosen for the frequency of operation.  |  |
| RF-OUT and DC-IN   | 3          | RF output and bias pin. DC voltage is present on this pin; therefore a DC blocking capacitor is necessary for proper operation. An RF choke is needed to feed DC bias without loss of RF signal due to the bias connection, as shown in "Recommended Application Circuit". |  |
| GND 2,4 Connections to ground. Use via holes as shown in "Suggested Layout for PCB Design inductance for best performance. |            | Connections to ground. Use via holes as shown in "Suggested Layout for PCB Design" to reduce ground path inductance for best performance.  |  |

REV. Q ECO-024491 FRA-6SM+





# Monolithic Amplifier **ERA-6SM+**

DC to 4 GHz 50Ω

#### **ELECTRICAL SPECIFICATIONS AT +25°C AND 70 mA UNLESS NOTED OTHERWISE**

| Parameter  | Condition (GHz) | Min. | Тур.   | Max.  | Units |
|--|-----------------|------|--------|-------|-------|
| Frequency Range <sup>1</sup>   |                 | DC   |        | 4     | GHz   |
|  | 0.1             | 12   | 12.6   | 13.3  |       |
|  | 1.0             |      | 12.5   |       |       |
| Gain   | 2.0             | 11.1 | 11.7   | 12.3  | dB    |
|  | 3.0             |      | 11.7   |       |       |
|  | 4.0             | 9.8  | 10.3   | 10.8  |       |
|  | 0.1             |      | 0.0013 | .0025 |       |
|  | 1.0             |      | 0.0018 | .0035 |       |
| Magnitude of Gain Variation vs. Temperature<br>(Values Are Negative) | 2.0             |      | 0.0021 | .004  | dB/°C |
| (Values Ale Negative)  | 3.0             |      | 0.0025 | .005  |       |
|  | 4.0             |      | 0.0032 | .007  |       |
|  | 0.1             |      | 25     |       |       |
|  | 1.0             |      | 30     |       |       |
| Input Return Loss  | 2.0             |      | 35     |       | dB    |
|  | 3.0             |      | 33     |       |       |
|  | 4.0             |      | 28     |       |       |
|  | 0.1             |      | 35     |       |       |
|  | 1.0             |      | 24     |       |       |
| Output Return Loss   | 2.0             |      | 20     |       | dB    |
|  | 3.0             |      | 20     |       |       |
|  | 4.0             |      | 20     |       |       |
| Reverse Isolation  | 2.0             | 16   | 19     |       | dB    |
|  | 0.1             |      | +17.1  |       |       |
|  | 1.0             | +16  | +17.2  |       |       |
| Output Power @ 1 dB Compression                                      | 2.0             |      | +17.1  |       | dBm   |
|  | 3.0             |      | +16.2  |       |       |
|  | 4.0             |      | +14.7  |       |       |
|  | 0.1             |      | +17.1  |       |       |
|  | 1.0             |      | +17.2  |       |       |
| Saturated Output Power<br>(at 3 dB Compression)                      | 2.0             |      | +17.7  |       | dBm   |
| (at 3 db compression)  | 3.0             |      | +17.3  |       |       |
|  | 4.0             |      | +15.9  |       |       |
|  | 0.1             | +34  | +36.5  |       |       |
|  | 1.0             | +33  | +35    |       |       |
| Output IP3   | 2.0             | +31  | +33    |       | dBm   |
|  | 3.0             |      | +30    |       |       |
|  | 4.0             |      | +28.5  |       |       |
|  | 0.1             |      | 4.4    | 5.2   |       |
|  | 1.0             |      | 4.4    | 5.5   |       |
| Noise Figure   | 2.0             |      | 4.5    | 5.5   | dB    |
|  | 3.0             |      | 4.5    | 6     |       |
|  | 4.0             |      | 4.7    | 6     |       |
| Group Delay  | 2.0             |      | 80     |       | psec  |
| Recommended Device Operating Current                                 |                 |      | 70     |       | mA    |
| Device Operating Voltage   |                 | +4.7 | +5     | +5.3  | V     |
| Device Voltage Variation vs. Temperature at 70 mA                    |                 |      | -3.2   |       | mV/°C |
| Device Voltage Variation vs. Current at +25°C                        |                 |      | 11.8   |       | mV/mA |
| Thermal Resistance, Junction-to-Case <sup>2</sup>                    |                 |      | 143    |       | °C/W  |

<sup>1.</sup> Guaranteed specification DC-4 GHz. Low frequency cut off determined by external coupling capacitors.



<sup>2.</sup> Case is defined as ground leads.



## Monolithic Amplifier ERA-6SM+

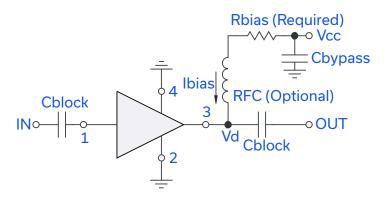
50Ω DC to 4 GHz

#### **ABSOLUTE MAXIMUM RATINGS**

| Parameter                          | Ratings         |  |
|------------------------------------|-----------------|--|
| Operating Temperature <sup>3</sup> | -45°C to +85°C  |  |
| Storage Temperature                | -65°C to +150°C |  |
| Operating Current                  | 85 mA           |  |
| Power Dissipation                  | 451 mW          |  |
| Input Power                        | +20 dBm         |  |

Permanent damage may occur if any of these limits are exceeded. These ratings are not intended for continuous normal operation.

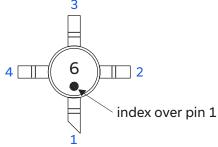
#### RECOMMENDED APPLICATION CIRCUIT



Test Board includes case, connectors, and components (in bold) soldered to PCB

| R BIAS |  |  |  |
|--------|--|--|--|
| Vcc    | "1%" Res. Values (Ohms)<br>for Optimum Biasing |  |  |
| 7      | 30.1   |  |  |
| 8      | 43.2   |  |  |
| 9      | 56.2   |  |  |
| 10     | 69.8   |  |  |
| 11     | 84.5   |  |  |
| 12     | 100  |  |  |
| 13     | 113  |  |  |
| 14     | 127  |  |  |
| 15     | 140  |  |  |
| 16     | 154  |  |  |
| 17     | 169  |  |  |
| 18     | 182  |  |  |
| 19     | 196  |  |  |
| 20     | 210  |  |  |

### **PRODUCT MARKING**



Markings in addition to model number designation may appear for internal quality control purposes.

<sup>3.</sup> Based on typical case temperature rise +5°C above ambient.



## Monolithic Amplifier

ERA-6SM+

50Ω DC to 4 GHz

## ADDITIONAL DETAILED TECHNICAL INFORMATION IS AVAILABLE ON OUR DASHBOARD. CLICK HERE

|  | Data Table  |
|--|---|
| Performance Data & Graphs                            | Swept Graphs  |
|  | S-Parameter (S2P Files) Data Set (.zip file)            |
| Case Style   | WW107 Plastic micro-x package, lead finish: Matte-tin   |
| Tape & Reel<br>Standard Quantities Available on Reel | F4<br>7" Reels with 20, 50, 100, 200, 500 or 1K devices |
| Suggested Layout for PCB Design                      | PL075   |
| Evaluation Board                                     | TB-408-6+   |
| Environmental Ratings                                | ENV08T2   |

#### **ESD RATING**

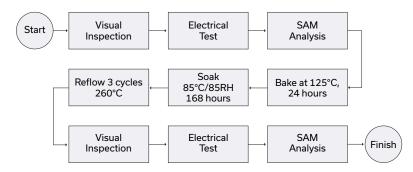
Human Body Model (HBM): Class 1B (500 V to < 1000 V) in accordance with ANSI/ESD STM 5.1 - 2001 Machine Model (MM): Class M1 (< 100 V) in accordance with ANSI/ESD STM 5.2 - 1999

#### **MSL RATING**

Moisture Sensitivity: MSL1 in accordance with IPC/JEDECJ-STD-020C

| No. | Test Required                   | Condition   | Standard                       | Quantity |
|-----|---------------------------------|---|--------------------------------|----------|
| 1   | Visual Inspection               | Low Power Microscope<br>Magnification 40x   | MIP-IN-0003<br>(MCT spec)      | 45 units |
| 2   | Electrical Test                 | Room Temperature  | SCD<br>(MCL spec)              | 45 units |
| 3   | SAM Analysis                    | Less than 10% growth in term of delamination  | J-Std-020C<br>(Jedec Standard) | 45 units |
| 4   | Moisture Sensitivity<br>Level 1 | Bake at 125°C for 24 hours<br>Soak at 85°C/85%RH for 168 hours<br>Reflow 3 cycles at 260°C peak | J-Std-020C<br>(Jedec Standard) | 45 units |

#### **MSL TEST FLOW CHART**



#### NOTES

- A. Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document.
- B. Electrical specifications and performance data contained in this specification document are based on Mini-Circuit's applicable established test performance criteria and measurement instructions.
- C. The parts covered by this specification document are subject to Mini-Circuits standard limited warranty and terms and conditions (collectively, "Standard Terms"); Purchasers of this part are entitled to the rights and benefits contained therein. For a full statement of the standard terms and the exclusive rights and remedies thereunder, please visit Mini-Circuits' website at www.minicircuits.com/terms/viewterm.html

